

Description

The 9DBV0541 is a member of IDT's Full-Featured PCIe family. The device has 5 output enables for clock management, and 3 selectable SMBus addresses. It has integrated terminations for direct connection to 100ohm transmission lines.

Recommended Application

PCIe Gen1–3 clock distribution in Storage, Networking, Computing, Consumer

Output Features

- Five 1–200MHz Low-Power (LP) HCSL DIF pairs with $Z_0 = 100\Omega$
- Easy AC-coupling to other logic families, see IDT application note [AN-891](#)

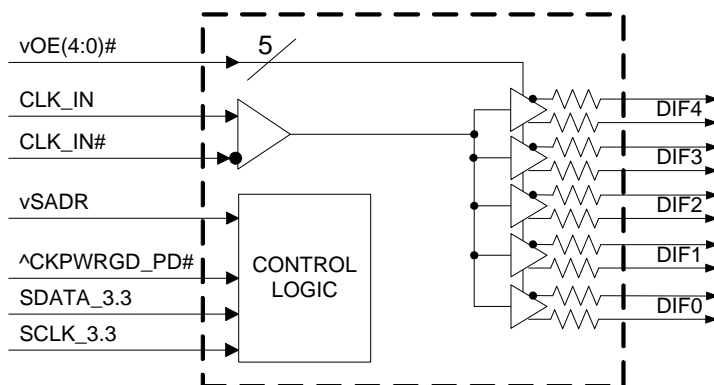
Key Specifications

- *Additive* cycle-to-cycle jitter < 5ps
- Output-to-output skew < 50ps
- *Additive* phase jitter is < 100fs rms for PCIe Gen3
- *Additive* phase jitter < 300fs rms (12kHz–20MHz at 125MHz)

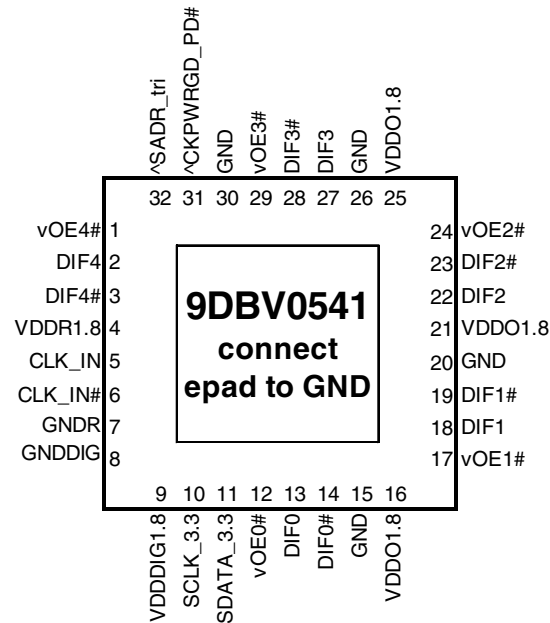
Features/Benefits

- 100 Ω direct connect; saves 20 resistors and 34mm² compared to standard HCSL
- 50mW typical power consumption; eliminates thermal concerns
- OE# pins; support DIF power management
- HCSL-compatible differential input; can be driven by common clock sources
- Spread spectrum compatible; allows EMI reduction
- SMBus-selectable features allow optimization to customer requirements
 - Slew rate for each output; allows tuning for various line length
 - Differential output amplitude; allows tuning for various application environments
- 1MHz to 200MHz operating frequency
- 3.3V tolerant SMBus interface works with legacy controllers
- Selectable SMBus addresses; multiple devices can easily share an SMBus segment
- Device contains default configuration; SMBus interface not required for device operation
- 32-pin 5 x 5 mm QFN; minimal board space

Block Diagram



Pin Configuration



32-pin QFN, 5 x 5 mm, 0.5mm pitch

^ prefix indicates internal 120kOhm pull-up resistor
 ^v prefix indicates internal 120kOhm pull-up AND pull-down resistor (biased to VDD/2)
 v prefix indicates internal 120kOhm pull-down resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write bit
State of SADR on first application of CKPWRGD_PD#	0	1101011	x
	M	1101100	x
	1	1101101	x

Power Management Table

CKPWRGD_PD#	CLK_IN	SMBus OEx bit	OEx# Pin	DIFx	
				True O/P	Comp. O/P
0	X	X	X	Low	Low
1	Running	0	X	Low	Low
1	Running	1	0	Running	Running
1	Running	1	1	Low	Low

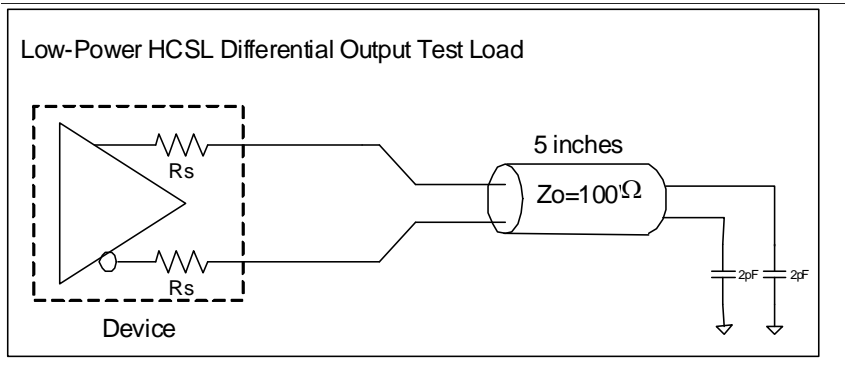
Power Connections

Pin Number		Description
VDD	GND	
4	7	Input receiver analog
9	8	Digital power
16, 21, 25	15,20,26,30	DIF outputs

Pin Descriptions

Pin#	Pin Name	Type	Pin Description
1	vOE4#	IN	Active low input for enabling output 4. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs.
2	DIF4	OUT	Differential true clock output.
3	DIF4#	OUT	Differential complementary clock output.
4	VDDR1.8	PWR	Power supply for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately. Nominally 1.8V.
5	CLK_IN	IN	True input for differential reference clock.
6	CLK_IN#	IN	Complementary input for differential reference clock.
7	GNDR	GND	Analog ground pin for the differential input (receiver).
8	GNDDIG	GND	Ground pin for digital circuitry.
9	VDDDIG1.8	PWR	1.8V digital power (dirty power).
10	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
11	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
12	vOE0#	IN	Active low input for enabling output 0. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs.
13	DIF0	OUT	Differential true clock output.
14	DIF0#	OUT	Differential complementary clock output.
15	GND	GND	Ground pin.
16	VDDO1.8	PWR	Power supply for outputs, nominally 1.8V.
17	vOE1#	IN	Active low input for enabling output 1. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs.
18	DIF1	OUT	Differential true clock output.
19	DIF1#	OUT	Differential complementary clock output.
20	GND	GND	Ground pin.
21	VDDO1.8	PWR	Power supply for outputs, nominally 1.8V.
22	DIF2	OUT	Differential true clock output.
23	DIF2#	OUT	Differential complementary clock output.
24	vOE2#	IN	Active low input for enabling output 2. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs.
25	VDDO1.8	PWR	Power supply for outputs, nominally 1.8V.
26	GND	GND	Ground pin.
27	DIF3	OUT	Differential true clock output.
28	DIF3#	OUT	Differential complementary clock output.
29	vOE3#	IN	Active low input for enabling output 3. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs.
30	GND	GND	Ground pin.
31	^CKPWRGD_PD#	IN	Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal 120kohm pull-up resistor.
32	^SADR_tri	LATCHED IN	Tri-level latch to select SMBus Address. It has an internal 120kohm pull up resistor. See SMBus Address Selection Table.
33	EPAD	GND	Connect epad to ground.

Test Loads



Alternate Terminations

The 9DBV0541 can easily drive LVPECL, LVDS, and CML logic. See [“AN-891 Driving LVPECL, LVDS, and CML Logic with IDT’s “Universal” Low-Power HCSL Outputs”](#) for details.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBV0541. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Applies to all VDD's	-0.5		2.5	V	1,2
Input Voltage	V _{IN}		-0.5		V _{DD} +0.5	V	1,3
Input High Voltage, SMBus	V _{IHSMB}	SMBus clock and data pins			3.6	V	1
Storage Temperature	T _s		-65		150	°C	1
Junction Temperature	T _j				125	°C	1
Input ESD Protection	ESD prot	Human Body Model	2000			V	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.5V.

Electrical Characteristics—Clock Input Parameters

T_A = T_{COM} or T_{IND}; Supply voltages per normal operation conditions; see Test Loads for loading conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V _{CROSS}	Cross over voltage	150		900	mV	1
Input Swing - DIF_IN	V _{SWING}	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	V _{IN} = V _{DD} , V _{IN} = GND	-5		5	μA	
Input Duty Cycle	d _{tin}	Measurement from differential waveform	40		60	%	1
Input Jitter - Cycle to Cycle	J _{DIFn}	Differential measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Slew rate measured through +/-75mV window centered around differential zero.

Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

TA = T_{COM} or T_{IND}; Supply voltages per normal operation conditions; see Test Loads for loading conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	1.7	1.8	1.9	V	
Ambient Operating Temperature	T _{COM}	Commercial range	0	25	70	°C	1
	T _{IND}	Industrial range	-40	25	85	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus	0.75 V _{DD}		V _{DD} + 0.3	V	
Input Mid Voltage	V _{IM}	Single-ended tri-level inputs ('_tri' suffix)	0.4 V _{DD}		0.6 V _{DD}	V	
Input Low Voltage	V _{IL}	Single-ended inputs, except SMBus	-0.3		0.25 V _{DD}	V	
Input Current	I _{IN}	Single-ended inputs, V _{IN} = GND, V _{IN} = VDD	-5		5	μA	
	I _{INP}	Single-ended inputs V _{IN} = 0 V; inputs with internal pull-up resistors V _{IN} = VDD; inputs with internal pull-down resistors	-200		200	μA	
Input Frequency	F _{in}		1		200	MHz	2
Pin Inductance	L _{pin}				7	nH	1
Capacitance	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,6
	C _{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T _{STAB}	From V _{DD} power-up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation Frequency PCIe	f _{MODINPCIe}	Allowable frequency for PCIe applications (Triangular modulation)	30		33	kHz	
Input SS Modulation Frequency non-PCIe	f _{MODIN}	Allowable frequency for non-PCIe applications (Triangular modulation)	0		66	kHz	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	1		3	clocks	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	μs	1,3
Tfall	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	V _{ILSMB}	V _{DDSMB} = 3.3V, see note 4 for V _{DDSMB} < 3.3V			0.8	V	4
SMBus Input High Voltage	V _{IHSMB}	V _{DDSMB} = 3.3V, see note 5 for V _{DDSMB} < 3.3V	2.1		3.3	V	5
SMBus Output Low Voltage	V _{OLSMB}	at I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	at V _{OL}	4			mA	
Nominal Bus Voltage	V _{DDSMB}	Bus Voltage	1.7		3.6	V	
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15V) to (Min VIH + 0.15V)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15V) to (Max VIL - 0.15V)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	7

¹ Guaranteed by design and characterization, not 100% tested in production.

² Control input must be monotonic from 20% to 80% of input swing.

³ Time from deassertion until outputs are > 200 mV.

⁴ For V_{DDSMB} < 3.3V, V_{ILSMB} < = 0.35V_{DDSMB}.

⁵ For V_{DDSMB} < 3.3V, V_{IHSMB} > = 0.65V_{DDSMB}.

⁶ DIF_IN input.

⁷ The differential input clock must be running for the SMBus to be active.

Electrical Characteristics–DIF Low Power HCSL Outputs

TA = T_{COM} or T_{IND}; Supply voltages per normal operation conditions; see Test Loads for loading conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew Rate	Trf	Scope averaging on, fast slew rate setting	1.6	2.6	4.3	V/ns	1,2,3
		Scope averaging on, slow slew rate setting	1.2	2.0	3.2	V/ns	1,2,3
Slew Rate Matching	ΔTrf	Slew rate matching, Scope averaging on		6	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope averaging on)	660	758	850	mV	7
Voltage Low	V _{LOW}		-150	43	150		7
Max Voltage	V _{max}	Measurement on single ended signal using absolute value. (Scope averaging off)		775	1150	mV	7
Min Voltage	V _{min}		-300	12			7
Vswing	Vswing	Scope averaging off	300	1428		mV	1,2
Crossing Voltage (abs)	V _{cross_abs}	Scope averaging off	250	391	550	mV	1,5
Crossing Voltage (var)	Δ-V _{cross}	Scope averaging off		14	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production. C_L = 2pF.

² Measured from differential waveform.

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ V_{cross} is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all V_{cross} measurements in any particular system. Note that this is a subset of V_{cross_min/max} (V_{cross} absolute) allowed. The intent is to limit V_{cross} induced modulation by setting Δ-V_{cross} to be smaller than V_{cross} absolute.

⁷ 660mV V_{high} is the minimum when VDDIO is >= 1.05V +/-5%. If VDDIO is < 1.05V +/-5%, the minimum V_{high} will be VDDIO_{min} - 250mV. For example for VDDIO = 0.9V +/-5%, V_{HIGHmin} will be 860mV - 250mV = 610mV.

Electrical Characteristics–Current Consumption

TA = T_{COM} or T_{IND}; Supply voltages per normal operation conditions; see Test Loads for loading conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I _{DDR}	VDDR at 100MHz		2	3	mA	
	I _{DDDIG}	VDDIG, all outputs at 100MHz		0.2	0.5	mA	
	I _{DDO}	VDDO1.8, all outputs at 100MHz		23	27	mA	
Powerdown Current	I _{DDRPD}	VDDR, CKPWRGD_PD# = 0		0.001	0.1	mA	2
	I _{DDDIGPD}	VDDDIG, CKPWRGD_PD# = 0		0.17	0.3	mA	2
	I _{DDOPD}	VDDO1.8, CKPWRGD_PD# = 0		0.4	0.8	mA	2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Input clock stopped.

Electrical Characteristics–Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{COM} or T_{IND}; Supply voltages per normal operation conditions; see Test Loads for loading conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle Distortion	t _{DCD}	Measured differentially, at 100MHz	-1	-0.1	1	%	1,3
Skew, Input to Output	t _{pdBYP}	V _T = 50%	1800	2342	3000	ps	1
Skew, Output to Output	t _{sk3}	V _T = 50%		37	50	ps	1,4
Jitter, Cycle to Cycle	t _{jcy c-cyc}	Additive Jitter		0.1	5	ps	1,2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform.

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock.

⁴ All outputs at default slew rate.

Electrical Characteristics–Phase Jitter Parameters

TA = T_{COM} or T_{IND}; Supply voltages per normal operation conditions; see Test Loads for loading conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
Additive Phase Jitter	t _{jphPCIeG1}	PCIe Gen 1		0.1	5	N/A	ps (p-p)	1,2,3,5
	t _{jphPCIeG2}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.1	0.4	N/A	ps (rms)	1,2,3,4,5
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.01	0.4	N/A	ps (rms)	1,2,3,4
	t _{jphPCIeG3}	PCIe Gen 3 (2-4MHz or 205MHz, CDR = 10MHz)		0.00	0.1	N/A	ps (rms)	1,2,3,4
	t _{jphSGMIIM0}	125MHz, 1.5MHz to 10MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		165	200	N/A	fs (rms)	1,6
t _{jphSGMIIM1}	125MHz, 12kHz to 20MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		251	300	N/A	fs (rms)	1,6	

¹ Guaranteed by design and characterization, not 100% tested in production.

² See <http://www.pcisig.com> for complete specs.

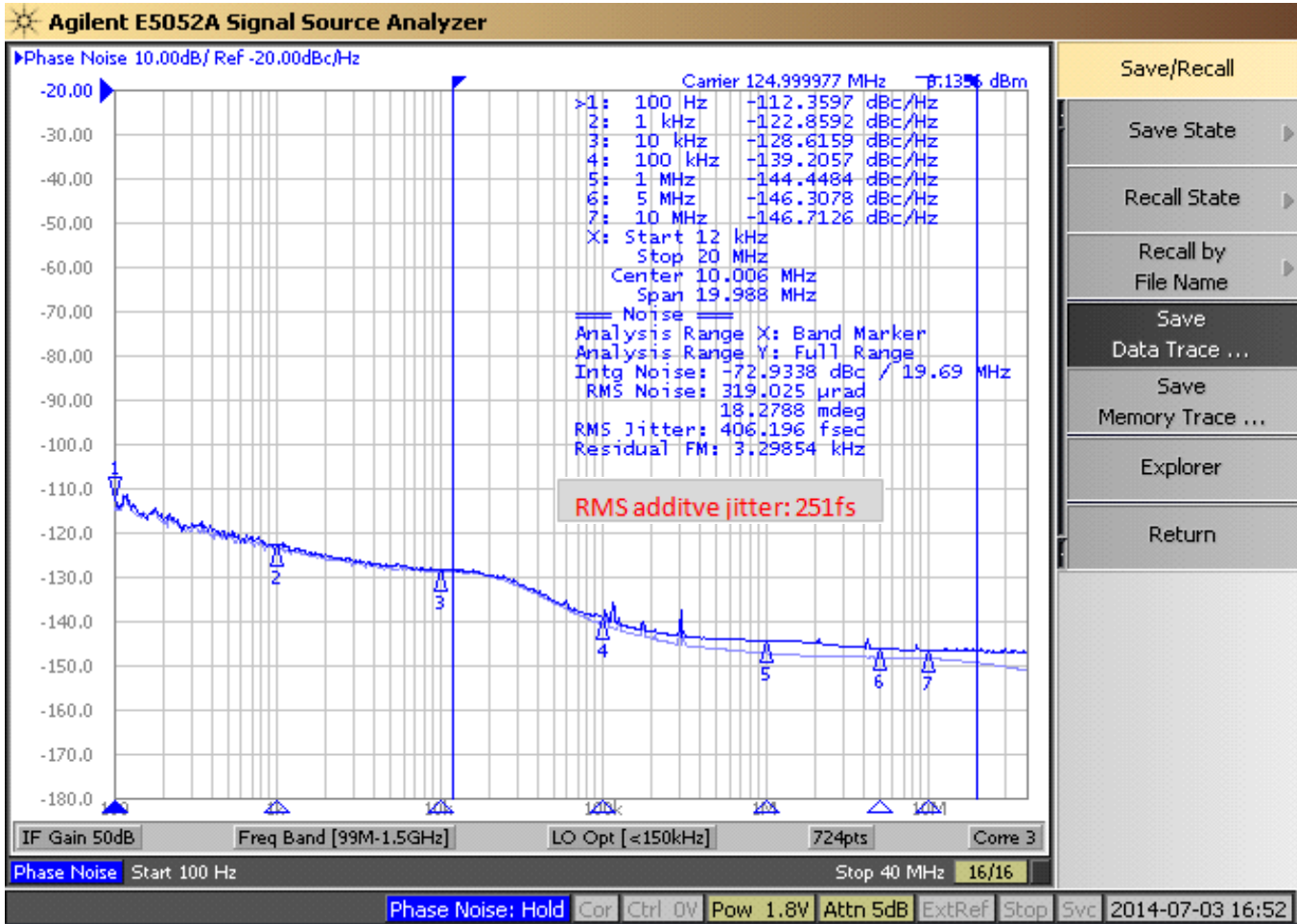
³ Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of 1-12.

⁴ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)² - (input jitter)²].

⁵ Driven by 9FGV0831 or equivalent.

⁶ Driven by Rohde & Schwarz SMA100.

Additive Phase Jitter Plot: 125M (12kHz to 20MHz)



General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will **acknowledge**
- Controller (host) starts sending Byte **N through Byte N+X-1**
- IDT clock will **acknowledge** each byte **one at a time**
- Controller (host) sends a stop bit

Index Block Write Operation		
Controller (Host)		IDT (Slave/Receiver)
T	starT bit	
Slave Address		
WR	WRite	
Beginning Byte = N		ACK
		ACK
Data Byte Count = X		ACK
Beginning Byte N		ACK
	X Byte	o
		o
		o
		o
Byte N + X - 1		ACK
P	stoP bit	

Note: SMBus Address is Latched on SADR pin.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will **acknowledge**
- IDT clock will send the data byte count = X
- IDT clock sends Byte **N+X-1**
- IDT clock sends **Byte 0 through Byte X (if X_(H) was written to Byte 8)**
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Index Block Read Operation		
Controller (Host)		IDT
T	starT bit	
Slave Address		
WR	WRite	
Beginning Byte = N		ACK
		ACK
RT	Repeat starT	
Slave Address		
RD	ReaD	
		ACK
ACK		
ACK		
	X Byte	o
		o
		o
		o
		Data Byte Count=X
		Beginning Byte N
		o
		o
		o
		Byte N + X - 1
N	Not acknowledge	
P	stoP bit	

SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					1
Bit 6	DIF OE3	Output Enable	RW	Low/Low	OE# pin control	1
Bit 5	DIF OE2	Output Enable	RW	Low/Low	OE# pin control	1
Bit 4	Reserved					1
Bit 3	DIF OE1	Output Enable	RW	Low/Low	OE# pin control	1
Bit 2	Reserved					1
Bit 1	DIF OE0	Output Enable	RW	Low/Low	OE# pin control	1
Bit 0	Reserved					1

1. A low on these bits will override the OE# pin and force the differential output Low/Low

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					0
Bit 6	Reserved					1
Bit 5	DIF OE4	Output Enable	RW	Low/Low	OE# pin control	1
Bit 4	Reserved					0
Bit 3	Reserved					1
Bit 2	Reserved					1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01 = 0.7V	1
Bit 0	AMPLITUDE 0		RW	10 = 0.8V	11 = 0.9V	0

1. A low on the DIF OE bit will override the OE# pin and force the differential output Low/Low

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					1
Bit 6	SLEWRATESEL DIF3	Slew Rate Selection	RW	Slow setting	Fast setting	1
Bit 5	SLEWRATESEL DIF2	Slew Rate Selection	RW	Slow setting	Fast setting	1
Bit 4	Reserved					1
Bit 3	SLEWRATESEL DIF1	Slew Rate Selection	RW	Slow setting	Fast setting	1
Bit 2	Reserved					1
Bit 1	SLEWRATESEL DIF0	Slew Rate Selection	RW	Slow setting	Fast setting	1
Bit 0	Reserved					1

SMBus Table: DIF Slew Rate Control Register

Byte 3	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					1
Bit 6	Reserved					1
Bit 5	Reserved					0
Bit 4	Reserved					0
Bit 3	Reserved					0
Bit 2	Reserved					1
Bit 1	Reserved					1
Bit 0	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow setting	Fast setting	1

Byte 4 is Reserved

SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Type	0	1	Default
Bit 7	RID3	Revision ID	R	A rev = 0000		0
Bit 6	RID2		R			0
Bit 5	RID1		R			0
Bit 4	RID0		R			0
Bit 3	VID3	VENDOR ID	R	0001 = IDT		0
Bit 2	VID2		R			0
Bit 1	VID1		R			0
Bit 0	VID0		R			1

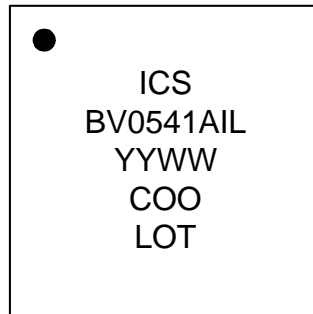
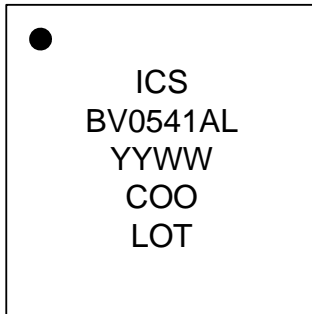
SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Type	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FG, 01 = DB 10 = DM, 11= DB fanout only		1
Bit 6	Device Type0		R			1
Bit 5	Device ID5	Device ID	R	000101 binary or 05 hex		0
Bit 4	Device ID4		R			0
Bit 3	Device ID3		R			0
Bit 2	Device ID2		R			1
Bit 1	Device ID1		R			0
Bit 0	Device ID0		R			1

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				0
Bit 6		Reserved				0
Bit 5		Reserved				0
Bit 4	BC4	Byte Count Programming	RW	Writing to this register will configure how many bytes will be read back, default is = 8 bytes.		0
Bit 3	BC3		RW			1
Bit 2	BC2		RW			0
Bit 1	BC1		RW			0
Bit 0	BC0		RW			0

Marking Diagrams



Notes:

1. "LOT" is the lot sequence number.
2. "COO" denotes country of origin.
3. YYWW is the last two digits of the year and week that the part was assembled.
4. Line 2: truncated part number
5. "L" denotes RoHS compliant package.
6. "I" denotes industrial temperature range device.

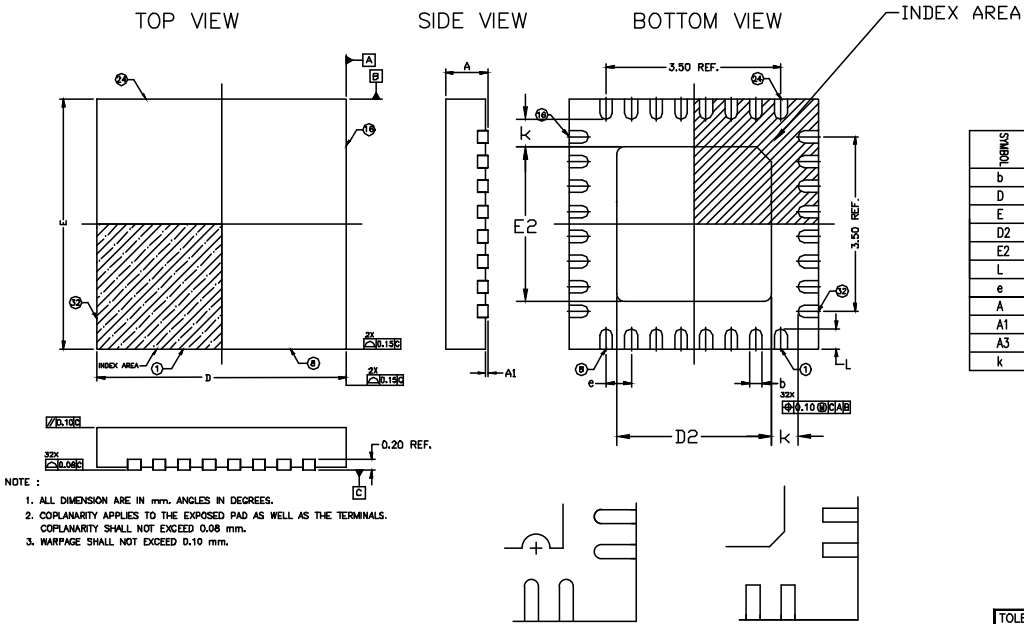
Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
Thermal Resistance	θ_{JC}	Junction to Case	NLG32	42	°C/W	1
	θ_{Jb}	Junction to Base		2.4	°C/W	1
	θ_{JA0}	Junction to Air, still air		39	°C/W	1
	θ_{JA1}	Junction to Air, 1 m/s air flow		33	°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow		28	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		27	°C/W	1

¹ePad soldered to board

Package Outline and Dimensions (NLG32)

REVISIONS			
REV	DESCRIPTION	DATE	APPROVED
00	INITIAL RELEASE	11/23/15	J.H
01	MODIFY DIMENSION TABLE	11/30/15	J.H



SYMBOL	DIMENSION		
	MIN	NOM	MAX
b	0.18	0.25	0.30
D	5.00 BSC		
E	5.00 BSC		
D2	3.00	3.10	3.20
E2	3.00	3.10	3.20
L	0.30	0.40	0.50
e	0.50 BSC		
A	0.80	0.90	1.00
A1	0.00	0.02	0.05
A3	0.2 REF		
k	0.55		

- NOTE :
1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
 2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS. COPLANARITY SHALL NOT EXCEED 0.08 mm.
 3. WARPAGE SHALL NOT EXCEED 0.10 mm.

PIN #1 ID OPTION

TOLERANCES UNLESS SPECIFIED
 DECIMAL ANGULAR
 X± .1 ±1°
 XX± .05
 XXX± .030



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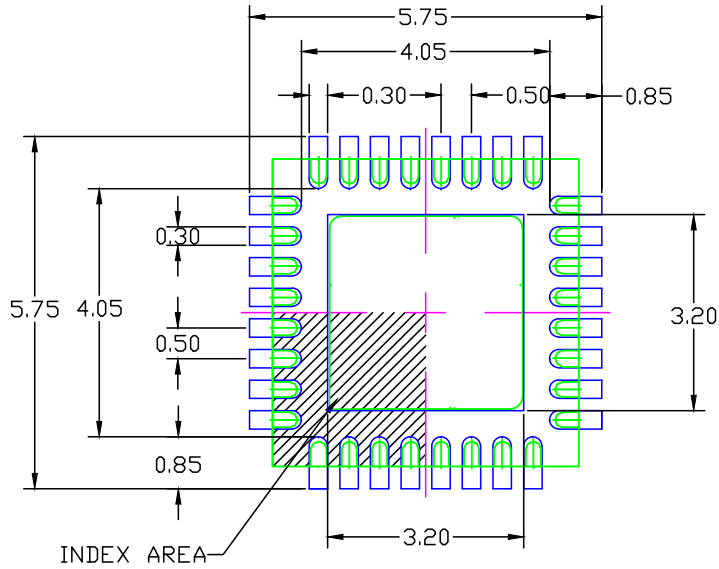
APPROVALS	DATE
DRAWN <i>blc</i>	11/23/15
CHECKED	

TITLE NL/NLG 32 PACKAGE OUTLINE
 5.0 x 5.0 mm BODY, EPAD 3.10 mm SQ
 0.50 mm PITCH QFN.

SIZE	DRAWING No.	REV
C	PSC-4171-03	01
DO NOT SCALE DRAWING		SHEET 1 OF 2

Package Outline and Dimensions (NLG32), cont.

REVISIONS			
REV	DESCRIPTION	DATE	APPROVED
00	INITIAL RELEASE	11/23/15	J.H
01	MODIFY DIMENSION TABLE	11/30/15	J.H



RECOMMENDED LAND PATTERN.

NOTES:

1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. TOP DOWN VIEW. AS VIEWED ON PCB.
3. COMPONENT OUTLINE SHOWS FOR REFERENCE IN GREEN.
4. LAND PATTERN IN BLUE. NSMD PATTERN ASSUMED.
5. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

TOLERANCES UNLESS SPECIFIED DECIMAL ANGULAR X± .1 ±1° XX± .05 XXX± .030		6024 Silver Creek Valley Rd San Jose, CA 95138 PHONE: (408) 284-8200 FAX: (408) 284-3572 www.IDT.com	TITLE NL/NLG 32 PACKAGE OUTLINE 5.0 x 5.0 mm BODY, EPAD 3.10 mm SQ 0.50 mm PITCH QFN.	
APPROVALS	DATE		SIZE	REV
DRAWN <i>PP</i>	12/20/06	C	01	
CHECKED		DRAWING No. PSC-4171-03		
DO NOT SCALE DRAWING			SHEET 2 OF 2	

Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DBV0541AKLF	Trays	32-pin QFN	0 to +70° C
9DBV0541AKLFT	Tape and Reel	32-pin QFN	0 to +70° C
9DBV0541AKILF	Trays	32-pin QFN	-40 to +85° C
9DBV0541AKILFT	Tape and Reel	32-pin QFN	-40 to +85° C

“LF” suffix to the part number are the Pb-Free configuration and are RoHS compliant.

“A” is the device revision designator (will not correlate with the datasheet revision).

Revision History

D	RDW	5/23/2016	Updated package outline drawings with latest version from Doc Control.	14, 15
E	RDW	3/10/2017	1. Removed "...Bypass Mode" reference in note 3 under Output Duty Cycle table. 2. Corrected spelling errors/typos. 3. Update Additive Phase Jitter conditions for PCIe Gen3.	8
F	RDW	5/30/2017	1. Corrected marking diagram for I-temp device.	13
G	C. Chen	10/27/2017	Updated ordering information to align with package outline drawings code.	16



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